Marcel A Verheijen

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The third column is the impact factor (IF) of the journal, and the fourth column is the number of citations of the article.

252 papers	9,931 citations	55 h-index	92 g-index
278 ext. papers	11,192 ext. citations	7.6 avg, IF	6.1 L-index

#	Paper	IF	Citations
252	Twinning superlattices in indium phosphide nanowires. *Nature*, **2008**, 456, 369-72	50.4	566
251	Quantized Majorana conductance. *Nature*, **2018**, 556, 74-79	50.4	382
250	Bright single-photon sources in bottom-up tailored nanowires. *Nature Communications*, **2012**, 3, 737	17.4	317
249	Single quantum dot nanowire LEDs. *Nano Letters*, **2007**, 7, 367-71	11.5	310
248	Direct band gap wurtzite gallium phosphide nanowires. *Nano Letters*, **2013**, 13, 1559-63	11.5	230
247	Difference between blocking and Néel temperatures in the exchange biased Fe3O4/CoO system. *Physical Review Letters*, **2000**, 84, 6102-5	7.4	215
246	Epitaxy of advanced nanowire quantum devices. *Nature*, **2017**, 548, 434-438	50.4	192
245	High-efficiency humidity-stable planar perovskite solar cells based on atomic layer architecture. *Energy and Environmental Science*, **2017**, 10, 91-100	35.4	184
244	The structure of different phases of pure C70 crystals. *Chemical Physics*, **1992**, 166, 287-297	2.3	176
243	Growth kinetics of heterostructured GaP-GaAs nanowires. *Journal of the American Chemical Society*, **2006**, 128, 1353-9	16.4	171
242	Epitaxial growth of InP nanowires on germanium. *Nature Materials*, **2004**, 3, 769-73	27	168
241	Waveguide Nanowire Superconducting Single-Photon Detectors Fabricated on GaAs and the Study of Their Optical Properties. *IEEE Journal of Selected Topics in Quantum Electronics*, **2015**, 21, 1-10	3.8	157
240	Supported Core/Shell Bimetallic Nanoparticles Synthesis by Atomic Layer Deposition. *Chemistry of Materials*, **2012**, 24, 2973-2977	9.6	132
239	Critical review of the current status of thickness measurements for ultrathin SiO2 on Si Part V: Results of a CCQM pilot study. *Surface and Interface Analysis*, **2004**, 36, 1269-1303	1.5	130
238	Interface formation of two- and three-dimensionally bonded materials in the case of GeTe-Sb□Te□ superlattices. *Nanoscale*, **2015**, 7, 19136-43	7.7	125
237	Direct-bandgap emission from hexagonal Ge and SiGe alloys. *Nature*, **2020**, 580, 205-209	50.4	124
236	Controlling the fixed charge and passivation properties of Si(100)/Al2O3 interfaces using ultrathin SiO2 interlayers synthesized by atomic layer deposition. *Journal of Applied Physics*, **2011**, 110, 093715	2.5	124

235	Synthesis of InP nanotubes. *Journal of the American Chemical Society*, **2003**, 125, 3440-1	16.4	123
234	Island growth in the atomic layer deposition of zirconium oxide and aluminum oxide on hydrogen-terminated silicon: Growth mode modeling and transmission electron microscopy. *Journal of Applied Physics*, **2004**, 96, 4878-4889	2.5	121
233	Efficiency enhancement of InP nanowire solar cells by surface cleaning. *Nano Letters*, **2013**, 13, 4113-7	11.5	119
232	Hexagonal Silicon Realized. *Nano Letters*, **2015**, 15, 5855-60	11.5	118
231	Atomic layer deposition for perovskite solar cells: research status, opportunities and challenges. *Sustainable Energy and Fuels*, **2017**, 1, 30-55	5.8	114
230	Influence of Oxygen Exposure on the Nucleation of Platinum Atomic Layer Deposition: Consequences for Film Growth, Nanopatterning, and Nanoparticle Synthesis. *Chemistry of Materials* , **2013**, 25, 1905-1911	9.6	112
229	Position-controlled epitaxial III-V nanowires on silicon. *Nanotechnology*, **2006**, 17, S271-S275	3.4	107
228	21.6%-Efficient Monolithic Perovskite/Cu(In,Ga)Se2 Tandem Solar Cells with Thin Conformal Hole Transport Layers for Integration on Rough Bottom Cell Surfaces. *ACS Energy Letters*, **2019**, 4, 583-590	20.1	106
227	Efficient water reduction with gallium phosphide nanowires. *Nature Communications*, **2015**, 6, 7824	17.4	106
226	Formation and electronic properties of InSb nanocrosses. *Nature Nanotechnology*, **2013**, 8, 859-64	28.7	106
225	Ultrahigh Capacitance Density for Multiple ALD-Grown MIM Capacitor Stacks in 3-D Silicon. *IEEE Electron Device Letters*, **2008**, 29, 740-742	4.4	104
224	Structural Characterization of Mesoporous Organosilica Films for Ultralow-kDielectrics. *Journal of Physical Chemistry B*, **2003**, 107, 4280-4289	3.4	104
223	From InSb nanowires to nanocubes: looking for the sweet spot. *Nano Letters*, **2012**, 12, 1794-8	11.5	102
222	Photoelectrochemical hydrogen production on InP nanowire arrays with molybdenum sulfide electrocatalysts. *Nano Letters*, **2014**, 14, 3715-9	11.5	100
221	Reversible switching of InP nanowire growth direction by catalyst engineering. *Nano Letters*, **2013**, 13, 3802-6	11.5	95
220	Growth and optical properties of axial hybrid III-V/silicon nanowires. *Nature Communications*, **2012**, 3, 1266	17.4	92
219	Asymmetric magnetic bubble expansion under in-plane field in Pt/Co/Pt: Effect of interface engineering. *Physical Review B*, **2015**, 91,	3.3	87
218	The role of surface energies and chemical potential during nanowire growth. *Nano Letters*, **2011**, 11, 1259-64	11.5	87

217	Epitaxial Growth of III-V Nanowires on Group IV Substrates. *MRS Bulletin*, **2007**, 32, 117-122	3.2	87
216	Surface passivated InAs/InP core/shell nanowires. *Semiconductor Science and Technology*, **2010**, 25, 024011	1.8	85
215	Crystal structure transfer in core/shell nanowires. *Nano Letters*, **2011**, 11, 1690-4	11.5	82
214	Three-dimensional morphology of GaP-GaAs nanowires revealed by transmission electron microscopy tomography. *Nano Letters*, **2007**, 7, 3051-5	11.5	79
213	Selective excitation and detection of spin states in a single nanowire quantum dot. *Nano Letters*, **2009**, 9, 1989-93	11.5	73
212	New orientationally ordered low-temperature superstructure in high-purity C60. *Physical Review Letters*, **1992**, 69, 1065-1068	7.4	73
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210	Atomic layer deposition of Pd and Pt nanoparticles for catalysis: on the mechanisms of nanoparticle formation. *Nanotechnology*, **2016**, 27, 034001	3.4	70
209	Remote p-doping of InAs nanowires. *Nano Letters*, **2007**, 7, 1144-8	11.5	70
208	Structural phase transitions in C 70. *Europhysics Letters*, **1993**, 21, 329-334	1.6	67
207	Electrical transport and Al doping efficiency in nanoscale ZnO films prepared by atomic layer deposition. *Journal of Applied Physics*, **2013**, 114, 024308	2.5	64
206	Generic nano-imprint process for fabrication of nanowire arrays. *Nanotechnology*, **2010**, 21, 065305	3.4	64
205	Low-temperature plasma-enhanced atomic layer deposition of 2-D MoS: large area, thickness control and tuneable morphology. *Nanoscale*, **2018**, 10, 8615-8627	7.7	63
204	Growth and Optical Properties of Direct Band Gap Ge/GeSn Core/Shell Nanowire Arrays. *Nano Letters*, **2017**, 17, 1538-1544	11.5	59
203	Tuning Material Properties of Oxides and Nitrides by Substrate Biasing during Plasma-Enhanced Atomic Layer Deposition on Planar and 3D Substrate Topographies. *ACS Applied Materials & Interfaces*, **2018**, 10, 13158-13180	9.5	59
202	Low-Temperature Plasma-Assisted Atomic-Layer-Deposited SnO as an Electron Transport Layer in Planar Perovskite Solar Cells. *ACS Applied Materials & Interfaces*, **2018**, 10, 30367-30378	9.5	59
201	Dynamic reconfiguration of van der Waals gaps within GeTe-SbTe based superlattices. *Nanoscale*, **2017**, 9, 8774-8780	7.7	57
200	Revisiting the Local Structure in Ge-Sb-Te based Chalcogenide Superlattices. *Scientific Reports*, **2016**, 6, 22353	4.9	57

199	Lattice vibrations in crystalline C70. *Physical Review B*, **1993**, 47, 7610-7613	3.3	57
198	Interface study on heterostructured GaP-GaAs nanowires. *Nanotechnology*, **2006**, 17, 4010-3	3.4	56
197	Rationally designed single-crystalline nanowire networks. *Advanced Materials*, **2014**, 26, 4875-9	24	55
196	Sub-nanometer dimensions control of core/shell nanoparticles prepared by atomic layer deposition. *Nanotechnology*, **2015**, 26, 094002	3.4	55
195	Direct-Write Atomic Layer Deposition of High-Quality Pt Nanostructures: Selective Growth Conditions and Seed Layer Requirements. *Journal of Physical Chemistry C*, **2013**, 117, 10788-10798	3.8	53
194	Atomic Layer Deposition of High-Purity Palladium Films from Pd(hfac)2 and H2 and O2 Plasmas. *Journal of Physical Chemistry C*, **2014**, 118, 8702-8711	3.8	52
193	Effective Surface Passivation of InP Nanowires by Atomic-Layer-Deposited AlO with PO Interlayer. *Nano Letters*, **2017**, 17, 6287-6294	11.5	52
192	High optical quality single crystal phase wurtzite and zincblende InP nanowires. *Nanotechnology*, **2013**, 24, 115705	3.4	50
191	Hexagonal close-packed C60. *Chemical Physics Letters*, **1994**, 219, 469-472	2.5	50
190	Low-temperature structure of solid C70. *Chemical Physics Letters*, **1994**, 223, 323-328	2.5	50
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187	Area-Selective Deposition of Ruthenium by Combining Atomic Layer Deposition and Selective Etching. *Chemistry of Materials*, **2019**, 31, 3878-3882	9.6	46
186	Tuning structural motifs and alloying of bulk immiscible Mo-Cu bimetallic nanoparticles by gas-phase synthesis. *Nanoscale*, **2013**, 5, 5375-83	7.7	46
185	Single-Crystalline Hexagonal Silicon-Germanium. *Nano Letters*, **2017**, 17, 85-90	11.5	45
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181	Uniform Atomic Layer Deposition of AlO on Graphene by Reversible Hydrogen Plasma Functionalization. *Chemistry of Materials*, **2017**, 29, 2090-2100	9.6	42
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176	Paired twins and [112] morphology in GaP nanowires. *Nano Letters*, **2010**, 10, 2349-56	11.5	39
175	Zinc incorporation via the vapor-liquid-solid mechanism into InP nanowires. *Journal of the American Chemical Society*, **2009**, 131, 4578-9	16.4	38
174	Position-controlled [100] InP nanowire arrays. *Applied Physics Letters*, **2012**, 100, 053107	3.4	37
173	Boosting Hole Mobility in Coherently Strained [110]-Oriented Ge-Si Core-Shell Nanowires. *Nano Letters*, **2017**, 17, 2259-2264	11.5	36
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169	Real time in situ spectroscopic ellipsometry of the growth and plasmonic properties of au nanoparticles on SiO2. *Nano Research*, **2012**, 5, 513-520	10	34
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165	Detection of the Presence of Gold Nanoparticles in Organs by Transmission Electron Microscopy. *Materials*, **2010**, 3, 4681-4694	3.5	29
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161	Chemical Analysis of the Interface between Hybrid Organic-Inorganic Perovskite and Atomic Layer Deposited AlO. *ACS Applied Materials & Interfaces*, **2019**, 11, 5526-5535	9.5	28
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159	Selective-area chemical beam epitaxy of in-plane InAs one-dimensional channels grown on InP(001), InP(111)B, and InP(011) surfaces. *Physical Review Materials*, **2019**, 3,	3.2	26
158	Low resistivity HfNx grown by plasma-assisted ALD with external rf substrate biasing. *Journal of Materials Chemistry C*, **2018**, 6, 3917-3926	7.1	25
157	HfSiO[sub 4] Dielectric Layers Deposited by ALD Using HfCl[sub 4] and NH[sub 2](CH[sub 2])[sub 3]Si(OC[sub 2]H[sub 5])[sub 3] Precursors. *Journal of the Electrochemical Society*, **2004**, 151, C716	3.9	25
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153	Crystal Phase Quantum Well Emission with Digital Control. *Nano Letters*, **2017**, 17, 6062-6068	11.5	23
152	Nitrogen-doping of bulk and nanotubular TiO2 photocatalysts by plasma-assisted atomic layer deposition. *Applied Surface Science*, **2015**, 330, 476-486	6.7	23
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146	Cracking the Si Shell Growth in Hexagonal GaP-Si Core-Shell Nanowires. *Nano Letters*, **2015**, 15, 2974-9	11.5	20

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136	Dopant Distribution in Atomic Layer Deposited ZnO:Al Films Visualized by Transmission Electron Microscopy and Atom Probe Tomography. *Chemistry of Materials*, **2018**, 30, 1209-1217	9.6	18
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130	Glucose-functionalized polystyrene particles designed for selective deposition of silver on the surface. *RSC Advances*, **2014**, 4, 62878-62881	3.7	17
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126	Bottom-Up Grown 2D InSb Nanostructures. *Advanced Materials*, **2019**, 31, e1808181	24	16
125	Plasma-assisted atomic layer deposition of conformal Pt films in high aspect ratio trenches. *Journal of Chemical Physics*, **2017**, 146, 052818	3.9	15
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122	Low-Temperature Phase-Controlled Synthesis of Titanium Di- and Tri-sulfide by Atomic Layer Deposition. *Chemistry of Materials*, **2019**, 31, 9354-9362	9.6	15
121	The Influence of Particle Size Distribution and Shell Imperfections on the Plasmon Resonance of Au and Ag Nanoshells. *Plasmonics*, **2017**, 12, 929-945	2.4	15
120	Atomic layer deposition of highly dispersed Pt nanoparticles on a high surface area electrode backbone for electrochemical promotion of catalysis. *Electrochemistry Communications*, **2017**, 84, 40-44	5.1	14
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117	Zirconia thin film preparation by wet chemical methods at low temperature. *Thin Solid Films*, **2010**, 519, 630-634	2.2	14
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115	Spin-Orbit Interaction and Induced Superconductivity in a One-Dimensional Hole Gas. *Nano Letters*, **2018**, 18, 6483-6488	11.5	14
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85	Plasma-assisted atomic layer deposition of HfNx: Tailoring the film properties by the plasma gas composition. *Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films*, **2017**, 35, 01B129	2.9	8
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